# NSN 5962-01-353-9511

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View Online at https://aerobasegroup.com/nsn/5962-01-353-9511

## Body Length:

Between 0.755 inches and 0.785 inches

## **Body Width:**

0.302 inches

# **Body Height:**

Between 0.145 inches and 0.175 inches

# **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Programmed and 3-state output and w/enable and monolithic

## Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

10 input

## **Current Rating Per Characteristic:**

125.00 milliamperes reverse current, dc absolute

# **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## **Capitance Rating Per Characteristic:**

5.00 input picofarads and 8.00 output picofarads

## Time Rating Per Chacteristic:

70.00 nanoseconds access

#### Memory Device Type:

Prom

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

16 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli



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